## NSN 5962-01-355-7295

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View Online at https://aerobasegroup.com/nsn/5962-01-355-7295

**Body Length:** 1.280 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.140 inches and 0.185 inches **Maximum Power Dissipation Rating:** 650.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and erasable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 22 input **Case Outline Source And Designator:** D-9 mil-m-38510 **Current Rating Per Characteristic:** 60.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Product Name:** 600 gate epld **Voltage Rating And Type Per Characteristic:** -2.0 volts power source and 7.0 volts power source **Capitance Rating Per Characteristic:** 20.00 input picofarads and 20.00 output picofarads **Time Rating Per Chacteristic:** 55.00 nanoseconds access **Memory Device Type:** Pal **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

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Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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